TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

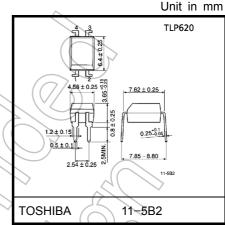
TLP620, TLP620-2, TLP620-4

Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA TLP620, -2 and -4 consists of a photo–transistor optically coupled to two gallium arsenide infrared emitting diode connected in inverse parallel.

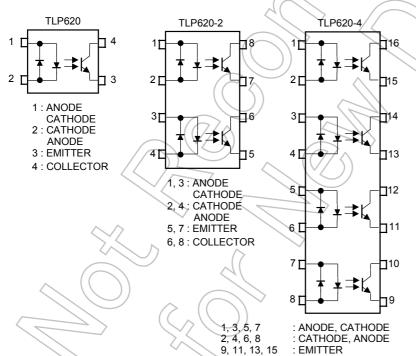
The TLP620–2 offers two isolated channels in an eight lead plastic DIP, while the TLP620–4 provides four isolated channels in a sixteen plastic DIP

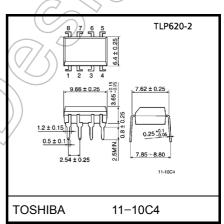
- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 50% (min.) Rank GB: 100% (min.)



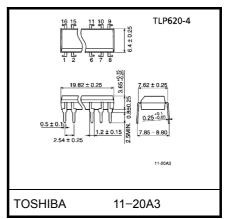
Weight: 0,26 g (typ.)

Pin Configurations (top view)





Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

10, 12, 14, 16 : COLLECTOR

	Made In Japan	Made In Thailand		
UL recognized	E67349	*1	E152349	*1
BSI approved	7426, 7427	*2	7426, 7427	*2

*1 UL1577

*2 BS EN60065: 2002, BS EN60950-1: 2002

• Isolation voltage: 5000V_{rms} (min.)

• Option (D4) type

VDE approved: DIN EN 60747-5-2, certificate no.40009302 Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

(Note) When an EN 60747-5-2 approved type is needed, please designate the "Option(D4)".

• Creepage distance: 6.4mm (min.) Clearance: 6.4mm (min.)

Insulation thickness: 0.4mm (min.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rat	ing TLP620-2	Unit
			TLP620	TLP620-4	
	Forward current	IF (RMS)	60	50	mA
	Forward current derating	ΔI _F / °C	–0.7 (Ta ≥ 39°C)	–0.5 (Ta ≥ 25°C)	mA / °C
Ω	Pulse forward current	IFP	1 (100µs pulse, 100pps)		Α
LED	Power dissipation (1 circuit)	PD	100	70	mW
	Power dissipation derating	ΔP _D /°C	-1.0	-0.7	mW / °C
	Junction temperature	(Ij))	12	25	°C
	Collector–emitter voltage	VCEO	5	V	
	Emitter-collector voltage) V _{ECO}		V	
Ä	Collector current	, lc \	I _C 50		mA
Detector	Collector power dissipation (1 circuit)	Pc	150	100	mW
	Collector power dissipation derating (1 circuit) (Ta ≥ 25°C)	ΔP _C / °C	-1.5	-1.0	mW / °C
	Junction temperature	/ ₹j	12	25	°C
Stor	age temperature range	T _{stg}	−55~125		°C
Оре	Operating temperature range		−55~100		°C
Lea	ad soldering temperature T _{sold}		260 (10s)		°C
Tota	Total package power dissipation		250	150	mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP _T / °C	-2.5	-1.5	mW / °C
Isolation voltage		BVS	5000 (AC, 1 min., RH ≤ 60%)		V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{CC}	_	5	24	V
Forward current	I _{F (RMS)}	_	16	20	mA
Collector current	IC	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F = ±10mA	1.0	1.15	1.3	V
LED	Forward current	lF	V _F = ±0.7V	7	2.5	20	μΑ
	Capacitance	C _T	V = 0, f = 1MHz		60/	_	pF
	Collector–emitter breakdown voltage	V (BR) CEO	I _C ≠ 0.5mA	55	_		V
ctor	Emitter–collector breakdown voltage	V (BR) ECO	IE = 0.1mA	7	-		V
Detector	Collector dark current	1	V _{CE} = 24V	_	10	100	nA
	Collector dark current	ICEO	V _{CE} = 24V, Ta = 85°C	1	2	50	μA
	Capacitance (collector to emitter)	C _{CE}	V _{CE} = 0, f = 1MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Current transfer ratio	10.115	I _C / I _F = ±5mA, V _{CE} = 5V	50	_	600	%
	IC / IF		100	_	600	%
Saturated CTR	lo /l= \alpha	IF = ±1mA, V _{CE} = 0.4V	_	60	-	%
	IC / IF (sat) Rank GB	30	1	ı	/0	
		I _C = 2.4mA, I _F = ±8mA	_	_	0.4	
Collector–emitter saturation voltage	VCE (sat)	VCE (sat) $I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB	_	0.2	_	V
			_	_	0.4	
Off-state collector current	IC (off)	$V_F = \pm 0.7V$, $V_{CE} = 24V$	_	1	10	μΑ
CTR symmetry	Ic (ratio)	$I_{C} (I_{F} = -5mA) / I_{C} (I_{F} = +5mA)$	0.33	1	3	_



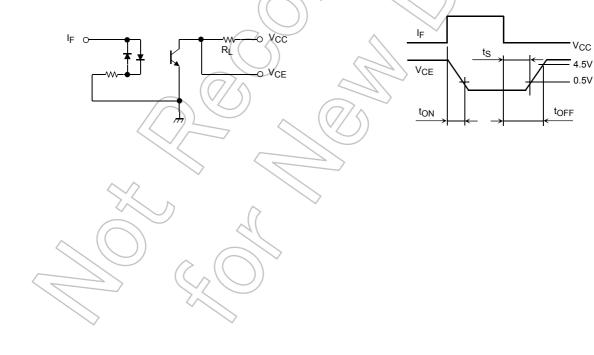
Isolation Characteristics (Ta = 25°C)

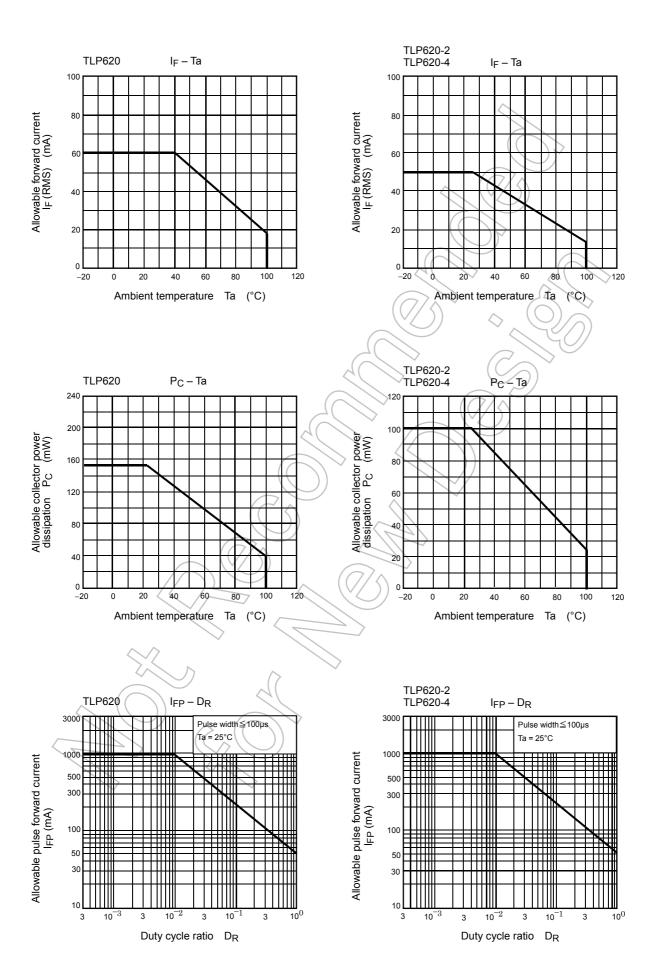
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0, f = 1MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500V	1×10 ¹²	10 ¹⁴	_	Ω
Isolation voltage		AC, 1 minute	5000	_	_	V
	BV_S	AC, 1 second, in oil	((-)	10000	_	V _{rms}
		DC, 1 minute, in oil	7	10000	_	V _{dc}

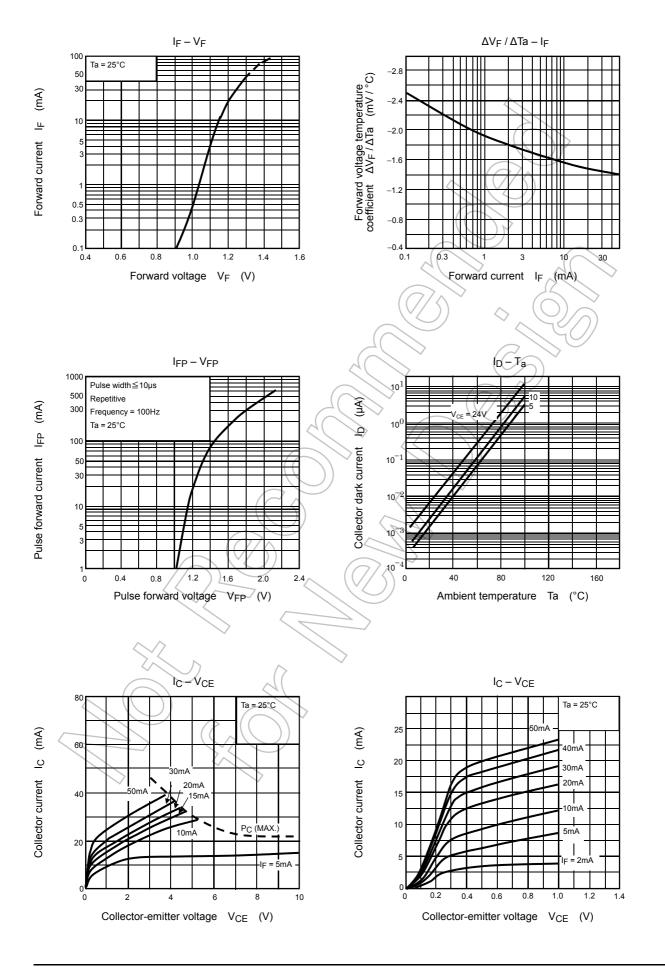
Switching Characteristics (Ta = 25°C)

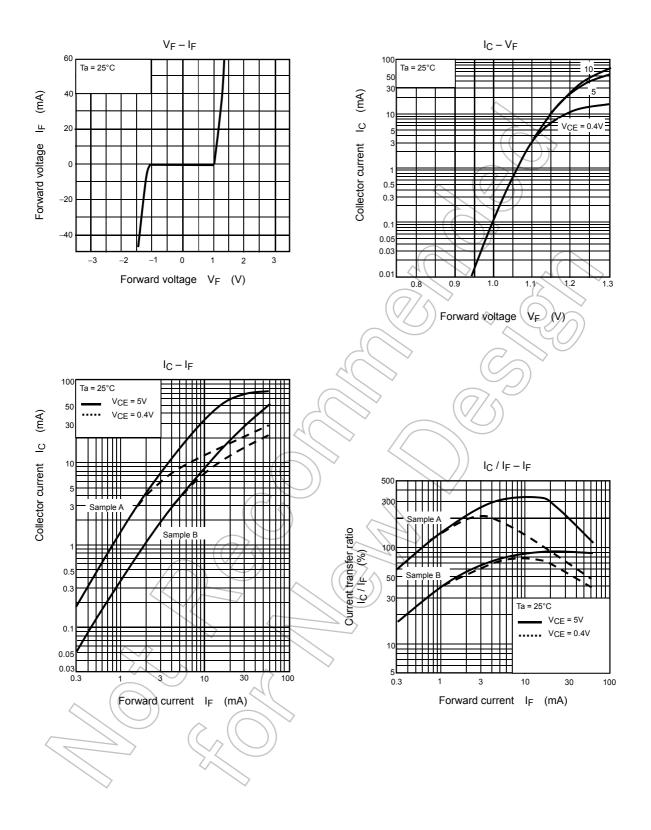
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r	40	_	2	\ <u></u>	
Fall time	t _f	V _{CC} = 10V	- /	3	_	
Turn-on time	t _{on}	I _C = 2mA R _L = 100Ω	-(()3	_	μs
Turn-off time	t _{off}	· ·	(+)	(3)	/ —	
Turn-on time	t _{ON}		7 -	> 2	_	
Storage time	ts	$R_L = 1.9k\Omega$ (Fig.1) $V_{CC} = 5V$, $I_F = \pm 16mA$	(9)	15	_	μs
Turn-off time	toff			25	_	

Fig. 1 Switching time test circuit

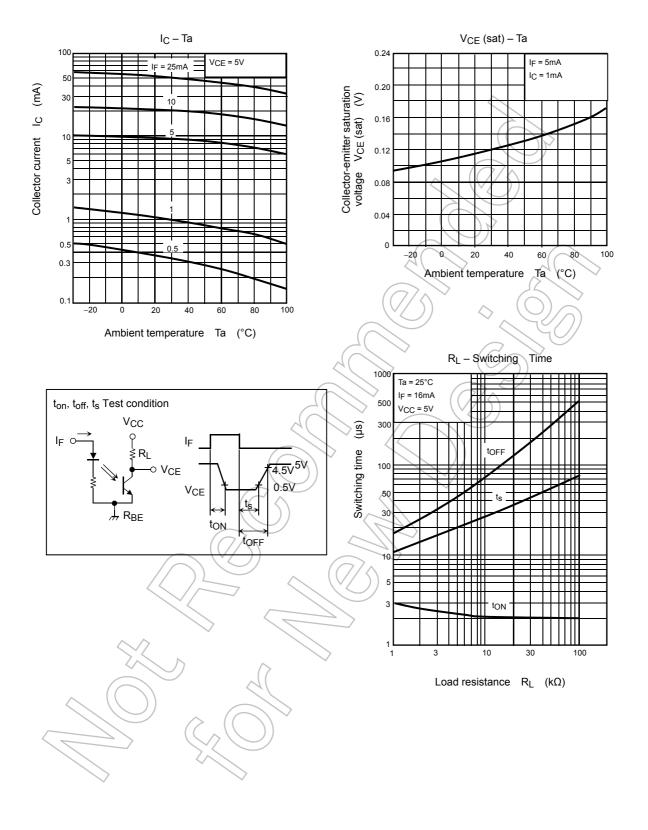








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